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Docket No.: M4065.0971/P971
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Luan C. Tran

Application No.: 10/663,710

Confirmation No.: 2238

Filed: September 17, 2003

Art Unit: 2818

For: METHOD OF FORMING DRAM ACCESS
TRANSISTORS (AS AMENDED)

Examiner: T. T. V. Ho

AMENDMENT UNDER 37 C.F.R. §1.312

MS AF
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Prior to the issuance of the above-identified U.S. patent application, please
replace the current title with the following new title:

METHOD OF FORMING DRAM ACCESS TRANSISTORS